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# Hex Buffer

# MC74LVX50

The MC74LVX50 is an advanced high speed CMOS buffer fabricated with silicon gate CMOS technology.

The internal circuit is composed of three stages, including a buffered output which provides high noise immunity and stable output. The inputs tolerate voltages up to 6.5 V, allowing the interface of 5.0 V systems to 3.0 V systems.

# Features

- High Speed:  $t_{PD}$  = 4.1 ns (Typ) at  $V_{CC}$  = 3.3 V
- Low Power Dissipation:  $I_{CC} = 2 \mu A$  (Max) at  $T_A = 25^{\circ}C$
- High Noise Immunity:  $V_{NIH} = V_{NIL} = 28\% V_{CC}$
- Power Down Protection Provided on Inputs
- Balanced Propagation Delays
- Designed for 2.0 V to 3.6 V Operating Range
- Low Noise:  $V_{OLP} = 0.5 V (Max)$
- These Devices are Pb-Free and are RoHS Compliant

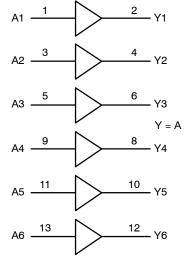


Figure 1. Logic Diagram

## FUNCTION TABLE

A Input	Y Output
L	L
Н	Н

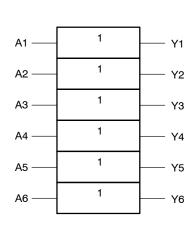


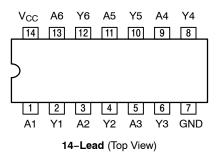
Figure 2. Logic Symbol



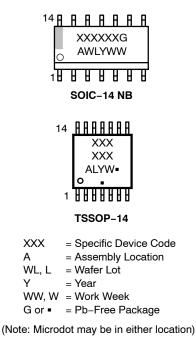
SOIC-14 NB D SUFFIX CASE 751A TSSOP-14 DT SUFFIX

DT SUFFIX CASE 948G

#### PIN ASSIGNMENT



# MARKING DIAGRAMS



## **ORDERING INFORMATION**

See detailed ordering and shipping information in the package dimensions section on page 5 of this data sheet.

# MAXIMUM RATINGS

Symbol	Parameter	Value	Unit
V <sub>CC</sub>	DC Supply Voltage	-0.5 to +6.5	V
V <sub>IN</sub>	DC Input Voltage	-0.5 to +6.5	V
V <sub>OUT</sub>	DC Output Voltage	$-0.5$ to $V_{CC}$ $+0.5$	V
Ι <sub>ΙΚ</sub>	DC Input Diode Current V <sub>I</sub> < GND	-20	mA
I <sub>OK</sub>	DC Output Diode Current V <sub>O</sub> < GND	±20	mA
I <sub>OUT</sub>	DC Output Sink Current	±25	mA
I <sub>CC</sub>	DC Supply Current per Supply Pin	±50	mA
T <sub>STG</sub>	Storage Temperature Range	-65 to +150	°C
ΤL	Lead Temperature, 1 mm from Case for 10 Seconds	260	°C
TJ	Junction Temperature under Bias	+ 150	°C
$\theta_{JA}$	Thermal Resistance (Note 1) SOIC TSSOP	116 150	°C/W
MSL	Moisture Sensitivity	Level 1	
F <sub>R</sub>	Flammability Rating Oxygen Index: 30% – 35%	UL 94-V0 @ 0.125 in	
$V_{\text{ESD}}$	ESD Withstand Voltage Human Body Model (Note 2) Charged Device Model (Note 3)	> 2000 2000	V V
I <sub>Latchup</sub>	Latchup Performance Above V <sub>CC</sub> and Below GND at 85°C (Note 4)	±300	mA

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. Measured with minimum pad spacing on an FR4 board, using 10 mm-by-1 inch, 2-ounce copper trace with no air flow.

2. Tested to EIA/JESD22-A114-A.

3. Tested to JESD22-C101-A.

4. Tested to EIA/JESD78.

## **RECOMMENDED OPERATING CONDITIONS**

Symbol	Parameter	Mir	า	Max	Unit
V <sub>CC</sub>	Supply Voltage	2.0	)	3.6	V
VI	Input Voltage (Note 5)	0		5.5	V
Vo	Output Voltage (HIGH or LOW State)	0		V <sub>CC</sub>	V
T <sub>A</sub>	Operating Free-Air Temperature	- 4	0	+ 85	°C
$\Delta t/\Delta V$	Input Transition Rise or Fall Rate $V_{CC} = 3.0 V \pm 0.000 V_{CC}$	.3 V 0		100	ns/V

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability. 5. Unused inputs may not be left open. All inputs must be tied to a high- or low-logic input voltage level.

NOTE: The 0, A of the package is equal to 1/Derating. Higher junction temperatures may affect the expected lifetime of the device per the table and figure below.

# DC ELECTRICAL CHARACTERISTICS

			v <sub>cc</sub>	٦	Γ <sub>A</sub> = 25°0	2	<b>T</b> <sub>A</sub> ≤	85°C	
Symbol	Parameter	Test Conditions	(V)	Min	Тур	Max	Min	Max	Unit
V <sub>IH</sub>	High-Level Input Voltage		2.0 3.0 3.6	1.5 2.0 2.4			1.5 2.0 2.4		V
VIL	Low-Level Input Voltage		2.0 3.0 3.6			0.5 0.8 0.8		0.5 0.8 0.8	V
V <sub>OH</sub>	High-Level Output Voltage (V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub> )	$I_{OH} = -50 \ \mu A$ $I_{OH} = -50 \ \mu A$ $I_{OH} = -4 \ m A$	2.0 3.0 3.0	1.9 2.9 2.58	2.0 3.0		1.9 2.9 2.48		V
V <sub>OL</sub>	Low-Level Output Voltage (V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub> )	$I_{OL} = 50 \ \mu A$ $I_{OL} = 50 \ \mu A$ $I_{OL} = 4 \ m A$	2.0 3.0 3.0		0.0 0.0	0.1 0.1 0.36		0.1 0.1 0.44	V
I <sub>IN</sub>	Input Leakage Current	$V_{IN} = 5.5 V \text{ or GND}$	0 to 3.6			±0.1		±1.0	μΑ
I <sub>CC</sub>	Quiescent Supply Current	$V_{IN} = V_{CC}$ or GND	3.6			2.0		20.0	μA

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

#### AC ELECTRICAL CHARACTERISTICS Input tr = tf = 3.0 ns

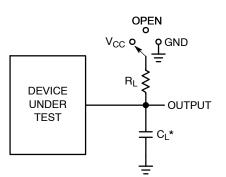
				1	Γ <sub>A</sub> = 25°0	2	<b>T</b> <sub>A</sub> ≤	85°C	
Symbol	Parameter	Test Cond	litions	Min	Тур	Max	Min	Max	Unit
t <sub>PLH</sub> , t <sub>PHL</sub>	Propagation Delay, Input A to Y	V <sub>CC</sub> = 2.7 V	C <sub>L</sub> = 15 pF C <sub>L</sub> = 50 pF		5.4 7.9	10.1 13.6	1.0 1.0	12.5 16.0	ns
		$V_{CC} = 3.3 \text{ V} \pm 0.3 \text{ V}$	C <sub>L</sub> = 15 pF C <sub>L</sub> = 50 pF		4.1 6.6	6.2 9.7	1.0 1.0	7.5 11.5	
t <sub>OSHL</sub>	Output-to-Output Skew	V <sub>CC</sub> = 2.7 V	C <sub>L</sub> = 50 pF			1.5		1.5	ns
toslh	(Note 6)	$V_{CC}=3.3~V\pm\!0.3V$	C <sub>L</sub> = 50 pF			1.5		1.5	
C <sub>IN</sub>	Input Capacitance				4	10		10	pF
				Ту	pical (	25°C, V	<sub>CC</sub> = 3.3	V	
C <sub>PD</sub>	Power Dissipation Capacitance	(Note 7)				15			pF

 Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH-to-LOW (t<sub>OSHL</sub>) or LOW-to-HIGH (t<sub>OSLH</sub>); parameter guaranteed by design.
 C<sub>PD</sub> is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

 C<sub>PD</sub> is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation: I<sub>CC(OPR)</sub> = C<sub>PD</sub> • V<sub>CC</sub> • f<sub>in</sub> + I<sub>CC</sub>. C<sub>PD</sub> is used to determine the no–load dynamic power consumption; P<sub>D</sub> = C<sub>PD</sub> • V<sub>CC</sub><sup>2</sup> • f<sub>in</sub> + I<sub>CC</sub> • V<sub>CC</sub>.

# NOISE CHARACTERISTICS Input $t_r = t_f = 3.0$ ns, $C_L = 50$ pF, $V_{CC} = 3.3$ V

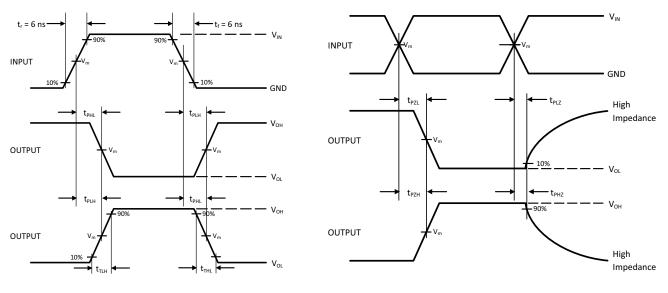
		T <sub>A</sub> = 25°C		
Symbol	Characteristic	Тур	Мах	Unit
V <sub>OLP</sub>	Quiet Output Maximum Dynamic V <sub>OL</sub>	0.3	0.5	V
V <sub>OLV</sub>	Quiet Output Minimum Dynamic V <sub>OL</sub>	-0.3	-0.5	V
V <sub>IHD</sub>	Minimum High Level Dynamic Input Voltage		2.0	V
V <sub>ILD</sub>	Maximum Low Level Dynamic Input Voltage		0.8	V



Test	Switch Position	CL	RL
t <sub>PLH</sub> / t <sub>PHL</sub>	Open	See AC	1 kΩ
t <sub>PLZ</sub> / t <sub>PZL</sub>	V <sub>CC</sub>	Charac- terisitcs	
t <sub>PHZ</sub> / t <sub>PZH</sub>	GND	Table	

 $^{\ast}\text{C}_{\text{L}}$  Includes probe and jig capacitance

Figure 3. Test Circuit



Device	V <sub>IN</sub> , V	V <sub>m</sub> , V
MC74LVX50	V <sub>CC</sub>	50% x V <sub>CC</sub>

Figure 4. Switching Waveforms

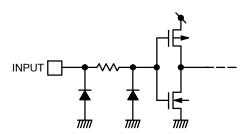


Figure 5. Input Equivalent Circuit

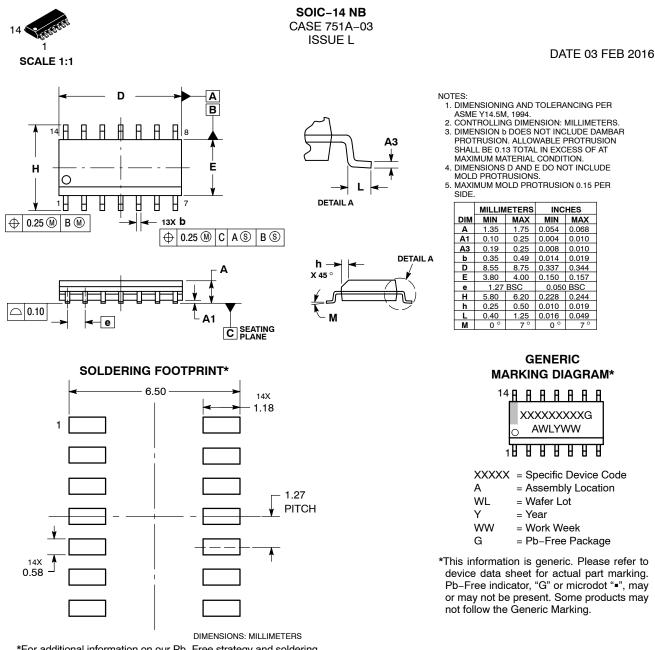
# MC74LVX50

## **ORDERING INFORMATION**

Device	Marking	Package	Shipping <sup>†</sup>
MC74LVX50DR2G	LVX50	SOIC-14	2500 Tape & Reel
MC74LVX50DTG	LVX 50	TSSOP-14	96 Units / Rail
MC74LVX50DTR2G	LVX 50	TSSOP-14	2500 Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

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\*For additional information on our Pb–Free strategy and soldering details, please download the **onsemi** Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

# **STYLES ON PAGE 2**

 
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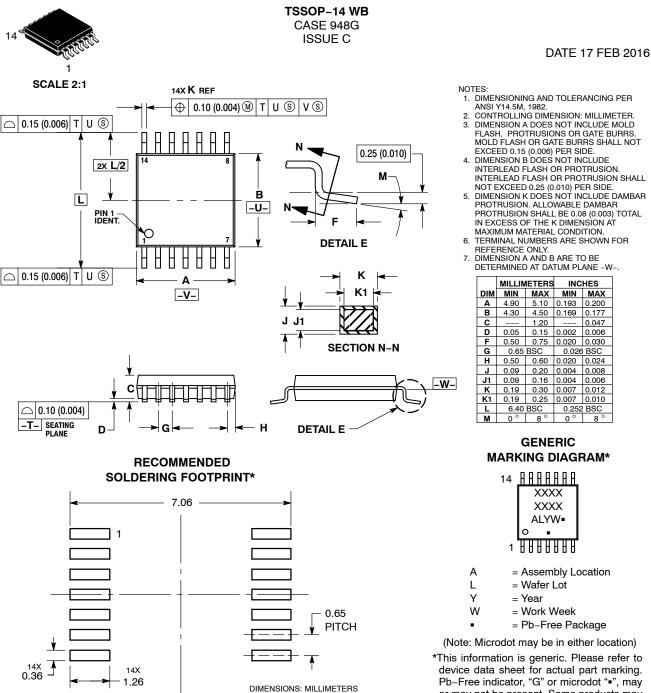
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STYLE 1: PIN 1. COMMON CATHODE 2. ANODE/CATHODE 3. ANODE/CATHODE 4. NO CONNECTION 5. ANODE/CATHODE 6. NO CONNECTION 7. ANODE/CATHODE 8. ANODE/CATHODE 9. ANODE/CATHODE 10. NO CONNECTION 11. ANODE/CATHODE 12. ANODE/CATHODE 13. NO CONNECTION 14. COMMON ANODE	STYLE 2: CANCELLED	STYLE 3: PIN 1. NO CONNECTION 2. ANODE 3. ANODE 4. NO CONNECTION 5. ANODE 6. NO CONNECTION 7. ANODE 8. ANODE 9. ANODE 10. NO CONNECTION 11. ANODE 12. ANODE 13. NO CONNECTION 14. COMMON CATHODE	STYLE 4: PIN 1. NO CONNECTION 2. CATHODE 3. CATHODE 4. NO CONNECTION 5. CATHODE 6. NO CONNECTION 7. CATHODE 8. CATHODE 10. NO CONNECTION 11. CATHODE 12. CATHODE 13. NO CONNECTION 14. COMMON ANODE
STYLE 5: PIN 1. COMMON CATHODE 2. ANODE/CATHODE 3. ANODE/CATHODE 4. ANODE/CATHODE 5. ANODE/CATHODE 6. NO CONNECTION 7. COMMON ANODE 8. COMMON CATHODE 9. ANODE/CATHODE 10. ANODE/CATHODE 11. ANODE/CATHODE 12. ANODE/CATHODE 13. NO CONNECTION 14. COMMON ANODE	STYLE 6: PIN 1. CATHODE 2. CATHODE 3. CATHODE 4. CATHODE 5. CATHODE 6. CATHODE 7. CATHODE 8. ANODE 9. ANODE 10. ANODE 11. ANODE 12. ANODE 13. ANODE 14. ANODE	STYLE 7: PIN 1. ANODE/CATHODE 2. COMMON ANODE 3. COMMON CATHODE 4. ANODE/CATHODE 5. ANODE/CATHODE 6. ANODE/CATHODE 7. ANODE/CATHODE 9. ANODE/CATHODE 10. ANODE/CATHODE 11. COMMON CATHODE 12. COMMON CATHODE 13. ANODE/CATHODE 14. ANODE/CATHODE	STYLE 8: PIN 1. COMMON CATHODE 2. ANODE/CATHODE 3. ANODE/CATHODE 4. NO CONNECTION 5. ANODE/CATHODE 6. ANODE/CATHODE 7. COMMON ANODE 9. ANODE/CATHODE 10. ANODE/CATHODE 11. NO CONNECTION 12. ANODE/CATHODE 13. ANODE/CATHODE 14. COMMON CATHODE

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\*For additional information on our Pb-Free strategy and soldering details, please download the onsemi Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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